TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK1826

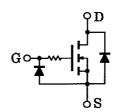
High Speed Switching Applications Analog Switch Applications

- 4 V gate drive
- Low threshold voltage: $V_{th} = 0.8 \sim 2.5 \text{ V}$
- High speed
- Enhancement-mode
- Small package

Marking

Equivalent Circuit



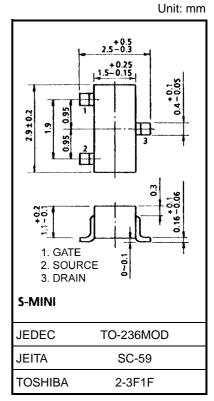


Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	50	V
Gate-source voltage	V_{GSS}	10	٧
DC drain current	I _D	50	mA
Drain power dissipation	P_{D}	200	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Note: This transistor is electrostatic sensitive device.

Please handle with caution.

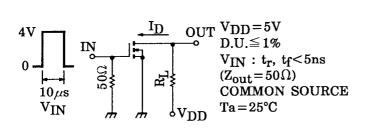


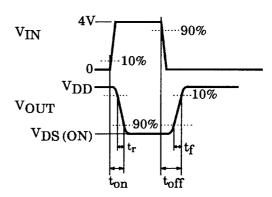
Weight: 0.012 g (typ.)

Electrical Characteristics (Ta = 25°C)

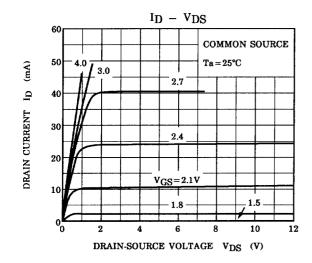
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = 10 V, V _{DS} = 0	_	_	1	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 100 \ \mu A, \ V_{GS} = 0$	50	_	_	V
Drain cut-off curre	ent	I _{DSS}	$V_{DS} = 50 \text{ V}, V_{GS} = 0$	_	_	1	μΑ
Gate threshold vo	ltage	V _{th}	$V_{DS} = 5 \text{ V}, I_{D} = 0.1 \text{ mA}$	0.8	_	2.5	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = 5 \text{ V}, I_{D} = 10 \text{ mA}$	20	_	_	mS
Drain-source ON resistance		R _{DS} (ON)	I_D = 10 mA, V_{GS} = 4.0 V	_	20	50	Ω
Input capacitance		C _{iss}	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	6.3	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	1.3	_	pF
Output capacitance		Coss	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	5.7	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 5 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 4.0 \text{ V}$	_	0.11	_	μЅ
	Turn-off time	t _{off}	$V_{DD} = 5 \text{ V}, I_{D} = 10 \text{ mA}, V_{GS} = 0 4.0 \text{ V}$	_	0.15	_	

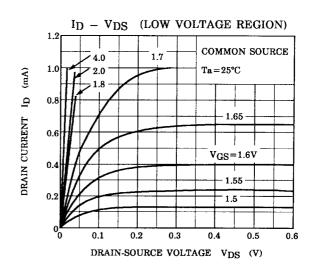
Switching Time Test Circuit

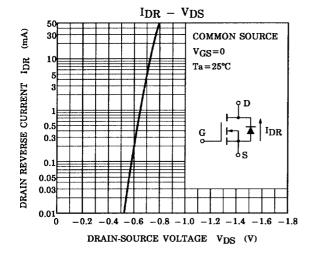


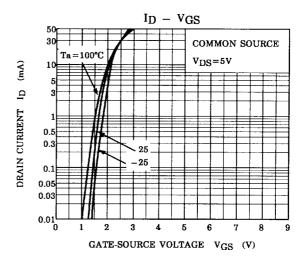


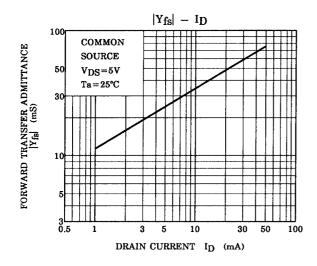
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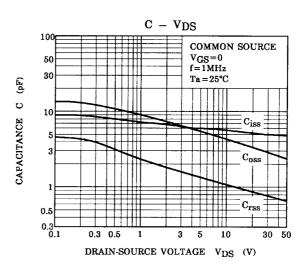




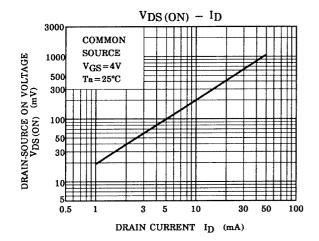


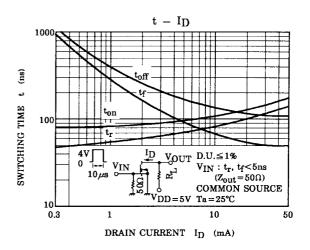


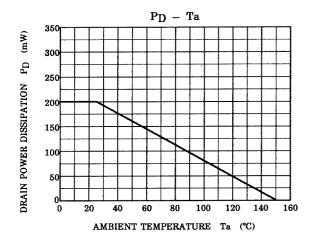




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